

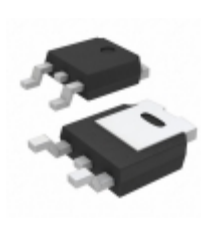
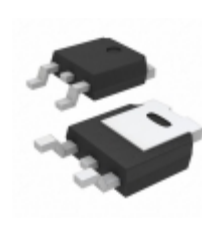


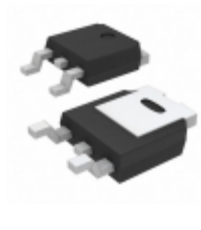


 life.augmented	<h2>STD4NK80ZT4</h2>
	<p>Hersteller-Teilenummer: STD4NK80ZT4</p> <p>Hersteller / Marke: STMicroelectronics</p> <p>Teil der Beschreibung: MOSFET N-CH 800V 3A DPAK</p> <p>Datenblätter:  STD4NK80ZT4.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 1993 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	STD4NK80ZT4
Hersteller	STMicroelectronics
Beschreibung	MOSFET N-CH 800V 3A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	1993 pcs Stock
Serie	SuperMESH™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	D-Pak
Verlustleistung (max)	80W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	800V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	3A (Tc)
Rds On (Max) @ Id, Vgs	3.5 Ohm @ 1.5A, 10V
VGS (th) (Max) @ Id	4.5V @ 50µA
Gate Charge (Qg) (Max) @ Vgs	22.5nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	575pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tape & Reel (TR)



















































STD4NK80ZT4 ist neu im Original, Suche STD4NK80ZT4 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie STD4NK80ZT4 STMicroelectronics mit Garantie und Vertrauen. Anfrage STD4NK80ZT4: Info@Y-IC.com

Sie können auch interessiert sein:

 STD4NK60Z-1 STMicroelectronics MOSFET N-CH 600V 4A IPAK	 STD4NK60ZT4 STMicroelectronics MOSFET N-CH 600V 4A DPAK	 STD4NS25T4 STMicroelectronics MOSFET N-CH 250V 4A DPAK	 STD4NK60ZT4 4N60 TO-252 TO-252 ST
 STD4NS25-1 ST STD4NS25-1 ST	 STD4NS25T4 Storm Interface MOSFET N-CH 250V 4A DPAK	 STD4NK80Z ST STD4NK80Z ST	 STD4NK80Z-1 STMicroelectronics MOSFET N-CH 800V 3A IPAK

heiße Teile

Mehr

 STD47N10F7AG	 STD49GK08	 STD49GK08B	 STD49GK12	 STD49GK12B
 STD49GK14	 STD49GK14B	 STD49GK16	 STD49GK16B	 STD49GK18
 STD49GK18B	 STD4N20-1	 STD4N52K3	 STD4N62K3	 STD4N80K5
 STD4NB40T4	 STD4NK50-1	 STD4NK50Z	 STD4NK50Z-1	 STD4NK50ZD
 STD4NK50ZT4	 STD4NK50ZT4G	 STD4NK60Z	 STD4NK60Z-1	 STD4NK60ZT4
 STD4NK80ZT4G	 STD4NS25	 STD4NS25-1	 STD4NS25T4	 STD4NS25T4
 STD5025NLS	 STD50N03	 STD50N03L	 STD50N03L-1	 STD50N03LT4
 STD50N06LTM-NL	 STD50NH02C	 STD50NH02L-1	 STD50NH02LT4	 STD52P3LLH6
 STD5406NT4G	 STD5406NT4G	 STD55N4F5	 STD55NF06-TR	 STD55NH02L
 STD55NH02LT4	 STD55NH22LL	 STD55NH2LL	 STD55NH2LL-1	 STD55NH2LL-1-E

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